

SHINDENGEN

VX-2 Series Power MOSFET

N-Channel Enhancement type

**2SK2197
(FP20W50VX2)**

500V 20A

FEATURES

- Input capacitance (C_{iss}) is small.
Especially, input capacitance at 0 bias is small.
- The static $R_{ds(on)}$ is small.
- The switching time is fast.

APPLICATION

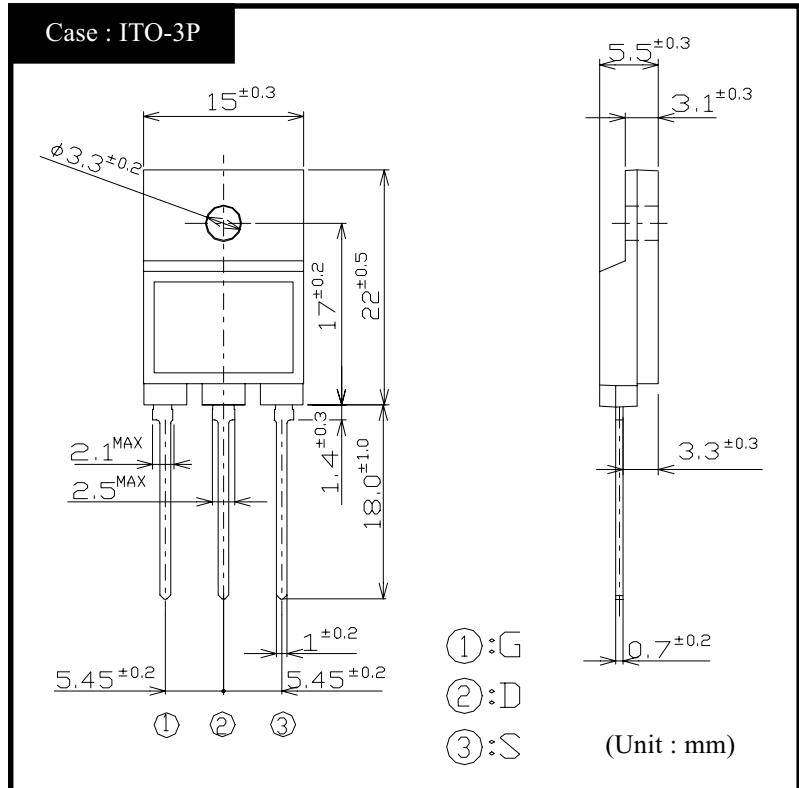
- Switching power supply of AC 100V input
- High voltage power supply
- Inverter

RATINGS

● Absolute Maximum Ratings ($T_c = 25^\circ\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-55~150	$^\circ\text{C}$
Channel Temperature	T_{ch}		150	
Drain-Source Voltage	V_{DSS}		500	V
Gate-Source Voltage	V_{GSS}		± 30	
Continuous Drain Current(DC)	I_D		20	A
Continuous Drain Current(Peak)	I_{DP}		60	
Continuous Source Current(DC)	I_S		20	
Total Power Dissipation	P_T		70	W
Single Pulse Avalanche Current	I_{AS}	$T_{ch} = 25^\circ\text{C}$	20	A
Dielectric Strength	V_{dis}	Terminals to case, AC 1 minute	2	kV
Mounting Torque	T_{OR}	(Recommended torque : 0.5N·m)	0.8	N·m

OUTLINE DIMENSIONS

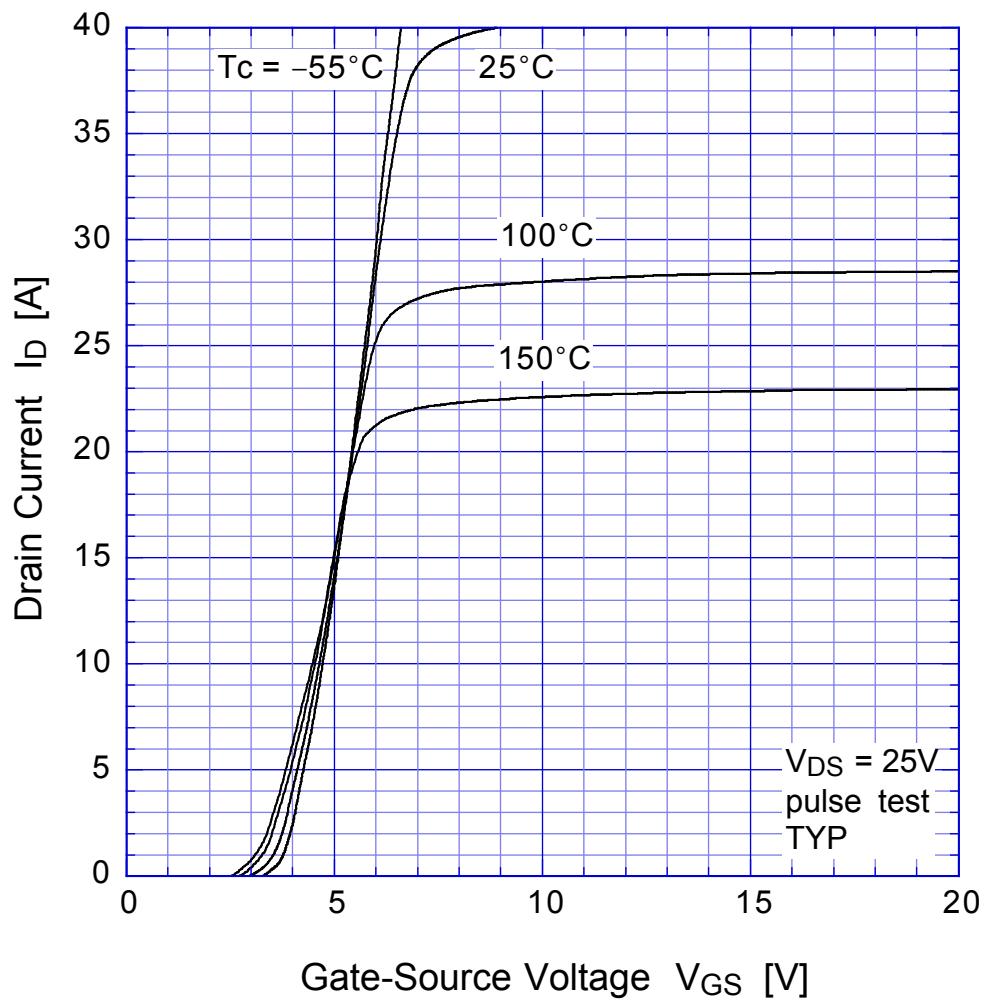


● Electrical Characteristics T_c = 25°C

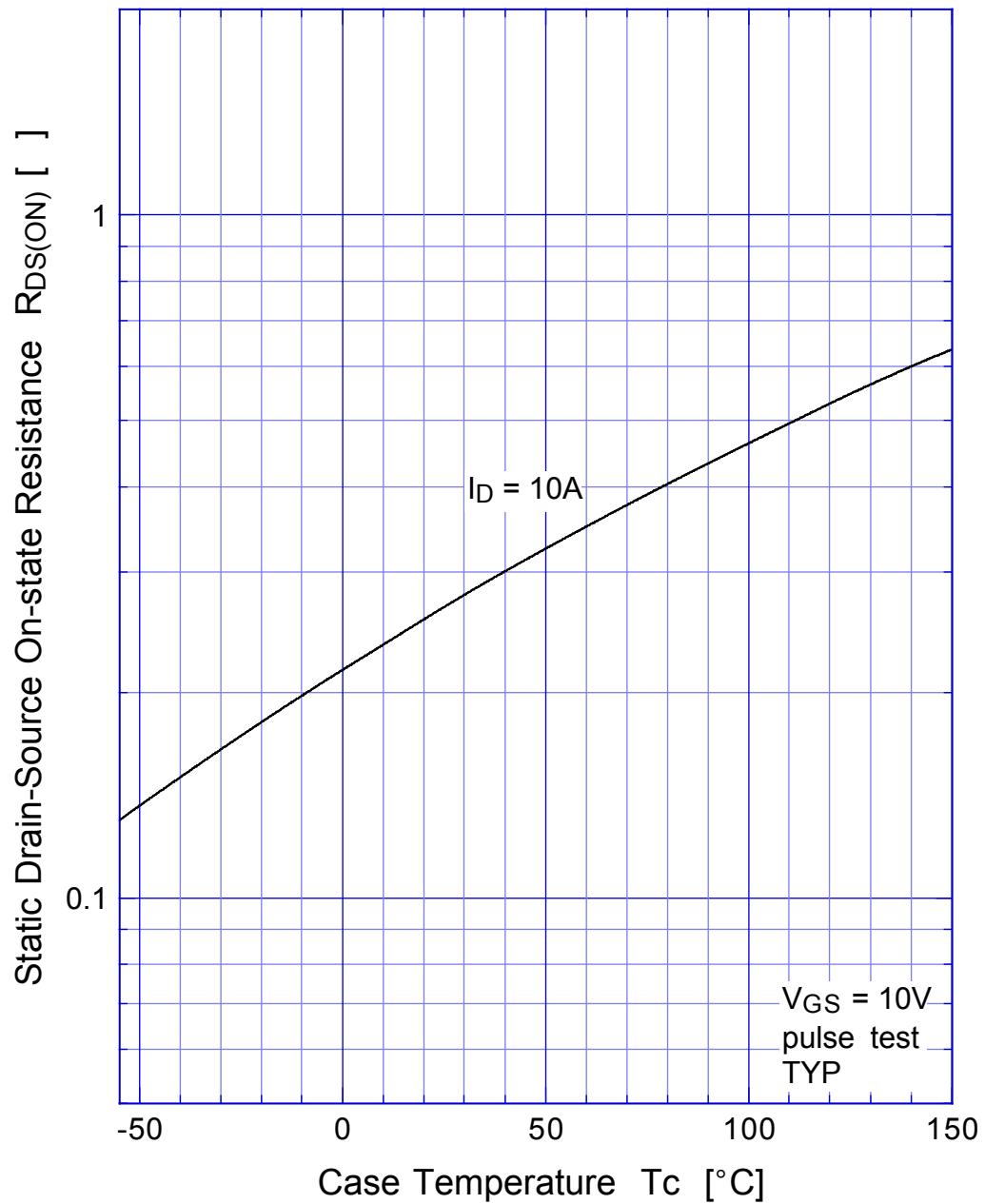
Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	V _{(BR)DSS}	ID = 1mA, V _{GS} = 0V	500			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 500V, V _{GS} = 0V			250	μA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = ±30V, V _{DS} = 0V			±0.1	
Forward Transconductance	g _s	ID = 10A, V _{DS} = 10V	6	15		S
Static Drain-Source On-state Resistance	R _{DSON}	ID = 10A, V _{GS} = 10V		0.27	0.35	Ω
Gate Threshold Voltage	V _{TH}	ID = 1mA, V _{DS} = 10V	2.5	3.0	3.5	V
Source-Drain Diode Forward Voltage	V _{SD}	I _S = 10A, V _{GS} = 0V			1.5	
Thermal Resistance	θ _{jc}	junction to case			1.78	°C/W
Total Gate Charge	Q _g	V _{DD} = 400V, V _{GS} = 10V, ID = 20A		85		nC
Input Capacitance	C _{iss}	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz	2400			pF
Reverse Transfer Capacitance	C _{rss}			170		
Output Capacitance	C _{oss}			500		
Turn-On Time	t _{on}	ID = 10A, V _{GS} = 10V, R _L = 15Ω	135	225		ns
Turn-Off Time	t _{off}			340	565	

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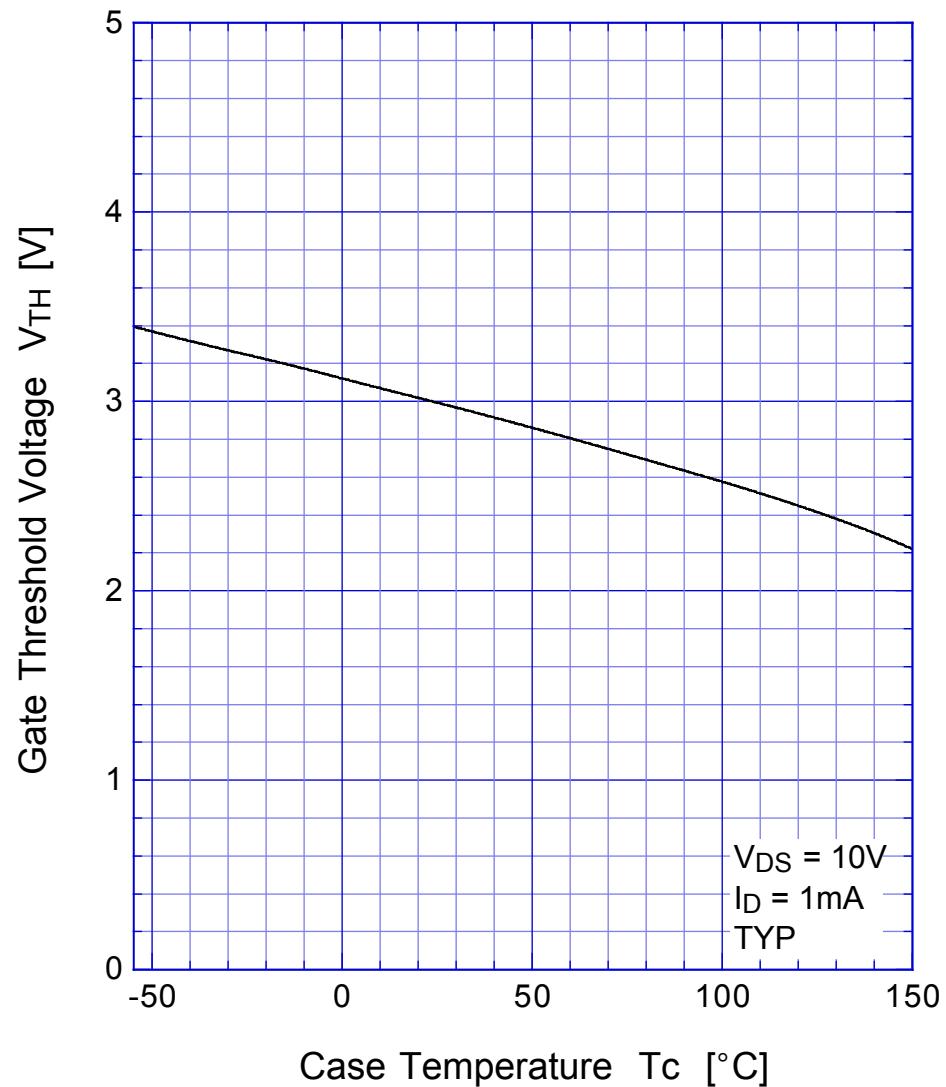
Transfer Characteristics



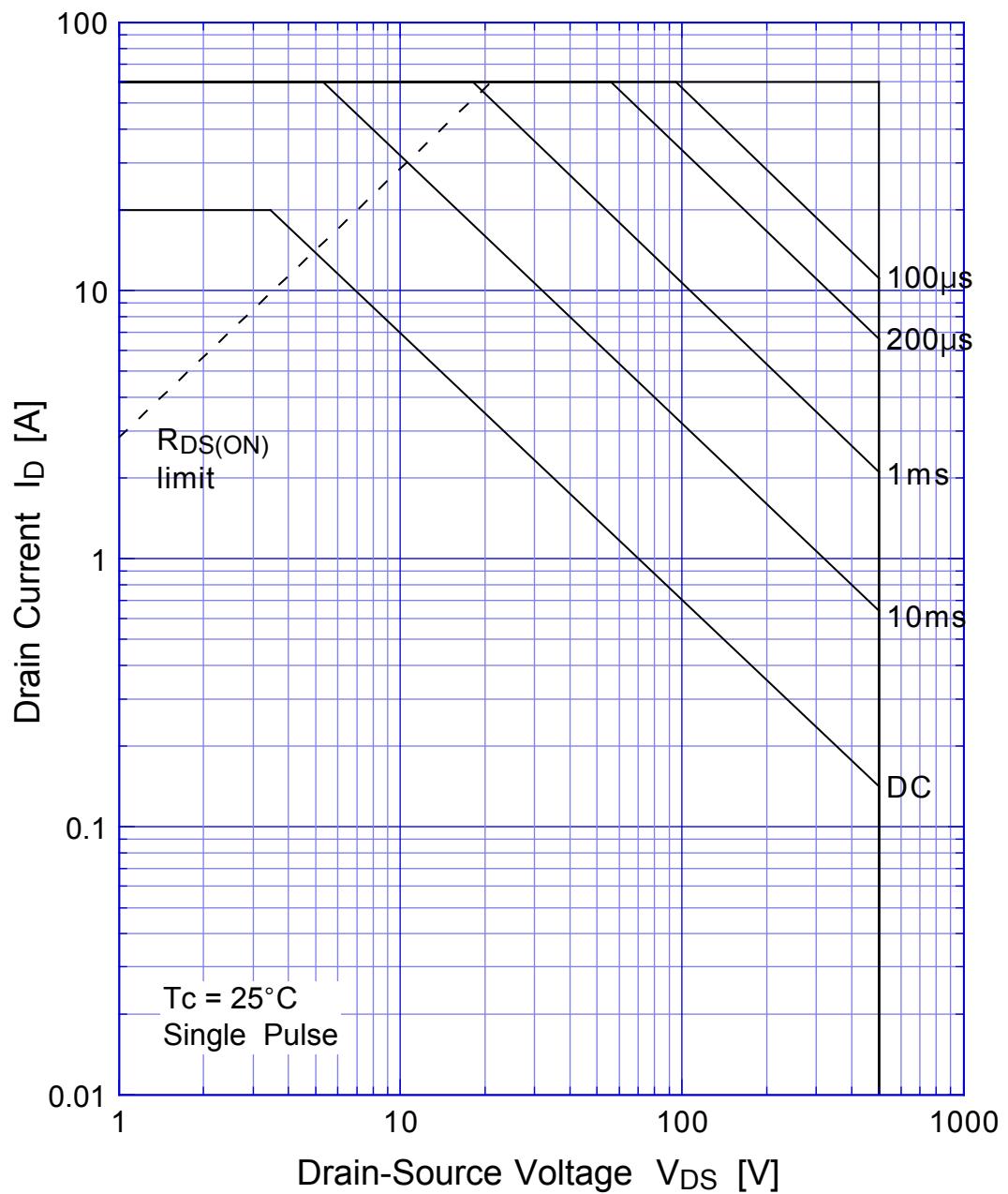
2SK2197 Static Drain-Source On-state Resistance



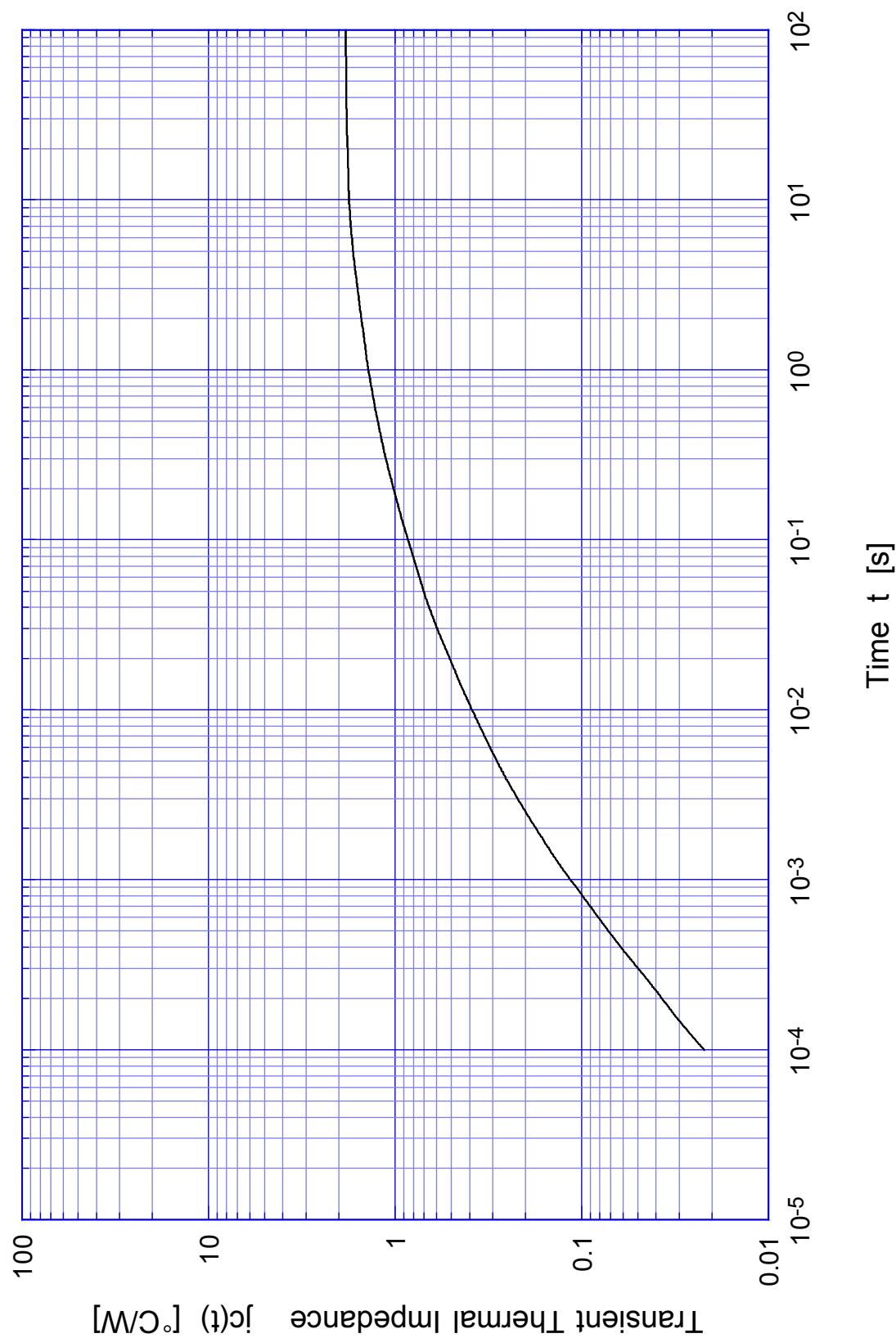
2SK2197 Gate Threshold Voltage



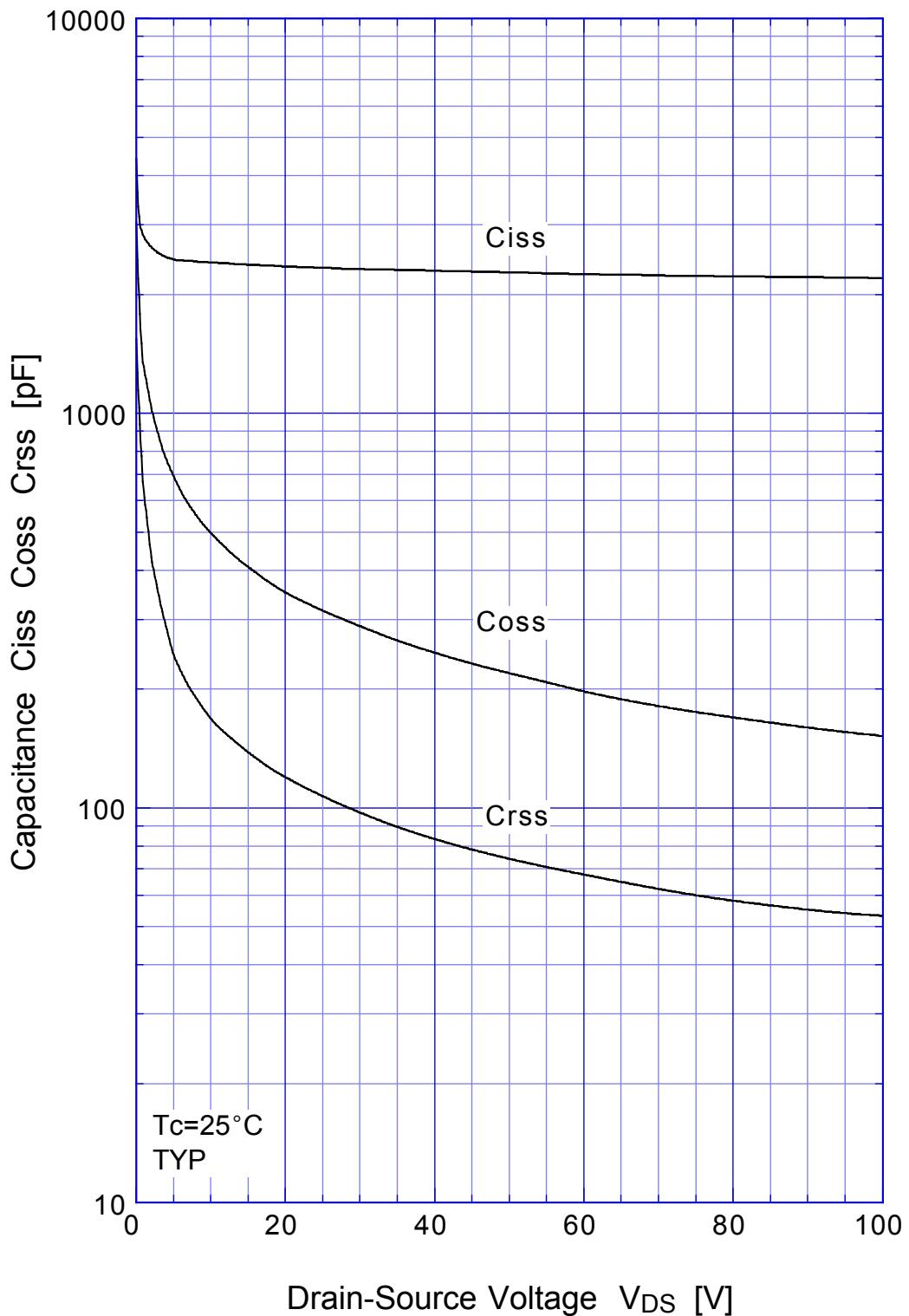
2SK2197 Safe Operating Area



2SK2197 Transient Thermal Impedance



2SK2197 Capacitance



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Power Derating



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Gate Charge Characteristics

